

DATA SHEET



N-Channel Silicon MOSFET MCH3477 — General-Purpose Switching Device **Applications**

Features

- · Ultrahigh-speed switching.
- 1.8V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	۱D		4.5	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	18	A
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² ×0.8mm)	1.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V
Zero-Gate Voltage Drain Current	IDSS	VDS=20V, VGS=0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	VDS=10V, ID=2A	2.0	3.4		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=2A, VGS=4.5V		29	38	mΩ
	R _{DS} (on)2	ID=1A, VGS=2.5V		43	61	mΩ
	RDS(on)3	ID=0.5A, VGS=1.8V		69	99	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		410		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		84		pF
Reverse Transfer Capacitance	Crss	VDS=10V, f=1MHz		59		pF

Marking : FJ

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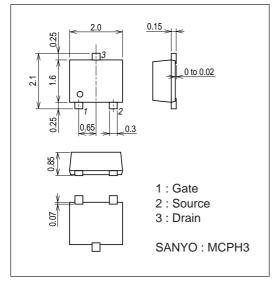
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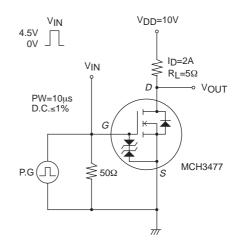
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		7.5		ns
Rise Time	tr	See specified Test Circuit.		26		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		38		ns
Fall Time	tf	See specified Test Circuit.		32		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =4.5V, I _D =4.5A		5.1		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4.5V, I _D =4.5A		0.7		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =4.5V, I _D =4.5A		1.7		nC
Diode Forward Voltage	VSD	IS=4.5A, VGS=0V		0.78	1.2	V

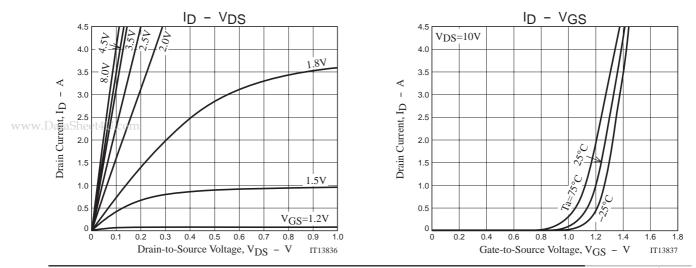
Package Dimensions

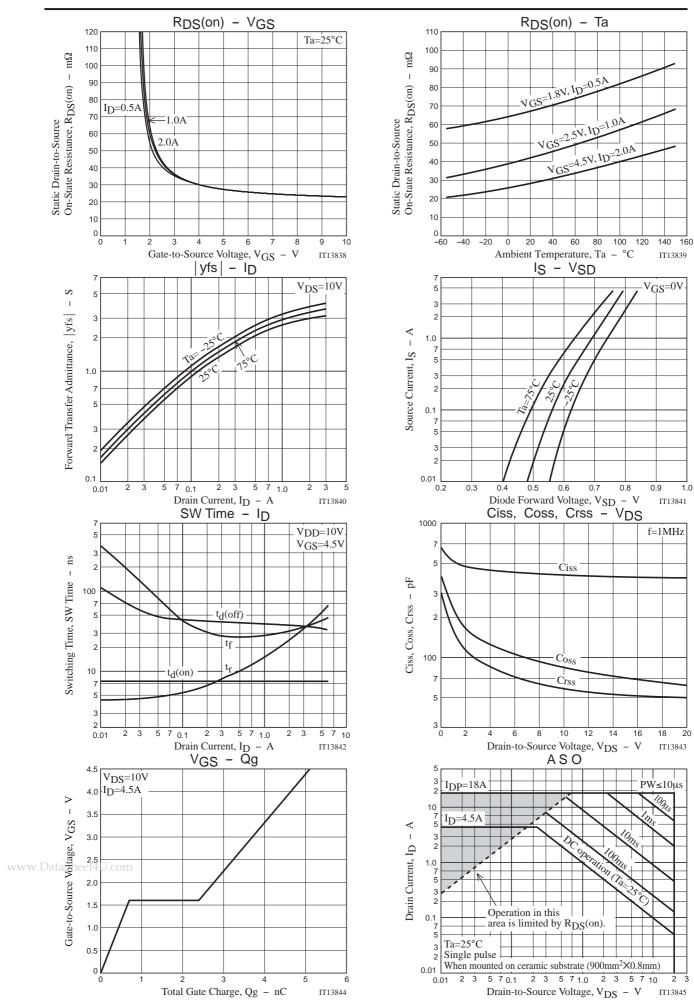
unit : mm (typ) 7019A-003



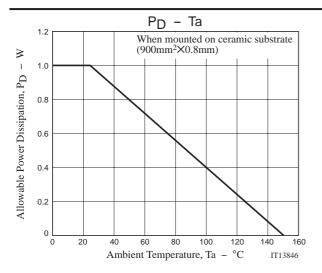
Switching Time Test Circuit







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Note on usage : Since the MCH3477 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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